

Amendments to the Specification

At the top of the first page, just under the title, insert:

Cross Reference to Related Applications

- - This application is the National Phase of International Application PCT/DK2003/000372 filed June 6, 2003 which designated the U.S. The noted application is incorporated herein by reference. - -

On page 1, please replace the paragraph just under Field of Invention with the following amended paragraph:

The invention relates to an optical microelectromechanical structure (MEMS) ~~according to claim 1~~ and a method of manufacturing a microelectromechanical structure (MEMS) ~~according to claim 33~~.

On page 4, please replace the paragraph beginning on line 28 with the following amended paragraph:

In an embodiment of the invention, said intermediate layer structure (IL) comprises at least two separated mutually joined layers, at least one of said mutually joined layers comprising an electrically insulating layer (22) and at least one of said mutually joined layers comprising a further layer (21).

On page 5, please replace the paragraph beginning on line 1 with the following amended paragraph:

In an embodiment of the invention, said intermediate layer structure (IL) comprises a handle layer (21) and an insulating layer (22) of an SOI wafer.

On page 7, please delete the paragraph beginning on line 25 and ending on line 26.